



YEA SHIN TECHNOLOGY CO., LTD

YS6988Z-5BB

## N-Channel Enhancement MOSFET

**VDS= 65V, ID= 35A**



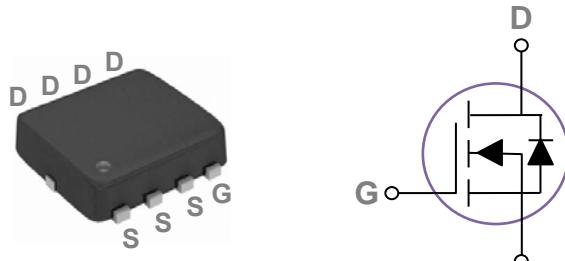
### Features

- 65V, 35A,  $R_{DS(ON)} = 16m\Omega$  @  $V_{GS} = 10V$
- Improved  $dv/dt$  capability
- Fast switching
- 100% EAS Guaranteed
- Green Device Available

### Applications

- Motor Drive
- Power Tools
- LED Lighting
- Quick Charger

### PPAK3x3 Pin Configuration



### Absolute Maximum Rating $T_c=25^\circ C$ unless otherwise noted

| Symbol    | Parameter  | Rating     | Units         |
|-----------|--|------------|---------------|
| $V_{DS}$  | Drain-Source Voltage                             | 65         | V             |
| $V_{GS}$  | Gate-Source Voltage                              | +20/-12    | V             |
| $I_D$     | Drain Current – Continuous ( $T_c=25^\circ C$ )  | 35         | A             |
|           | Drain Current – Continuous ( $T_c=100^\circ C$ ) | 22         | A             |
| $I_{DM}$  | Drain Current – Pulsed <sup>1</sup>              | 140        | A             |
| EAS       | Single Pulse Avalanche Energy <sup>2</sup>       | 9.1        | mJ            |
| IAS       | Single Pulse Avalanche Current <sup>2</sup>      | 13.5       | A             |
| $P_D$     | Power Dissipation ( $T_c=25^\circ C$ )           | 33.8       | W             |
|           | Power Dissipation – Derate above $25^\circ C$    | 0.27       | W/ $^\circ C$ |
| $T_{STG}$ | Storage Temperature Range                        | -55 to 150 | $^\circ C$    |
| $T_J$     | Operating Junction Temperature Range             | -55 to 150 | $^\circ C$    |

### Thermal Characteristics

| Symbol          | Parameter                              | Typ. | Max. | Unit           |
|-----------------|--|------|------|----------------|
| $R_{\theta JA}$ | Thermal Resistance Junction to ambient | ---  | 62   | $^\circ C / W$ |
| $R_{\theta JC}$ | Thermal Resistance Junction to Case    | ---  | 3.7  | $^\circ C / W$ |

# DEVICE CHARACTERISTICS

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Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)

### Off Characteristics

| Symbol                                     | Parameter  | Conditions  | Min. | Typ. | Max.      | Unit                      |
|--|--|---|------|------|-----------|---------------------------|
| $\text{BV}_{\text{DSS}}$                   | Drain-Source Breakdown Voltage                   | $V_{\text{GS}}=0\text{V}$ , $I_D=250\mu\text{A}$                                | 65   | ---  | ---       | V                         |
| $\Delta \text{BV}_{\text{DSS}}/\Delta T_J$ | $\text{BV}_{\text{DSS}}$ Temperature Coefficient | Reference to $25^\circ\text{C}$ , $I_D=1\text{mA}$                              | ---  | 0.03 | ---       | $\text{V}/^\circ\text{C}$ |
| $I_{\text{DSS}}$                           | Drain-Source Leakage Current                     | $V_{\text{DS}}=60\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=25^\circ\text{C}$ | ---  | ---  | 1         | $\mu\text{A}$             |
|  |  | $V_{\text{DS}}=48\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=85^\circ\text{C}$ | ---  | ---  | 10        | $\mu\text{A}$             |
| $I_{\text{GSS}}$                           | Gate-Source Leakage Current                      | $V_{\text{GS}}=\pm 20\text{V}$ , $V_{\text{DS}}=0\text{V}$                      | ---  | ---  | $\pm 100$ | $\text{nA}$               |

### On Characteristics

|                     |  |  |     |      |     |                            |
|---------------------|--|--|-----|------|-----|----------------------------|
| $R_{\text{DS(ON)}}$ | Static Drain-source On-Resistance <sup>3</sup> | $V_{\text{GS}}=10\text{V}$ , $I_D=12\text{A}$        | --- | 12.6 | 16  | $\text{m}\Omega$           |
|                     |  | $V_{\text{GS}}=4.5\text{V}$ , $I_D=5\text{A}$        | --- | 19   | 24  | $\text{m}\Omega$           |
| $V_{\text{GS(th)}}$ | Gate Threshold Voltage                         | $V_{\text{GS}}=V_{\text{DS}}$ , $I_D=250\mu\text{A}$ | 1   | 1.6  | 2.5 | V                          |
|                     |  |  | --- | -5.1 | --- | $\text{mV}/^\circ\text{C}$ |
| $g_{\text{fs}}$     | Forward Transconductance                       | $V_{\text{DS}}=10\text{V}$ , $I_D=3\text{A}$         | --- | 5    | --- | S                          |

### Dynamic and Switching Characteristics

|                     |                                   |  |     |      |      |          |
|---------------------|-----------------------------------|--|-----|------|------|----------|
| $Q_g$               | Total Gate Charge <sup>3,4</sup>  | $V_{\text{DS}}=30\text{V}$ , $V_{\text{GS}}=10\text{V}$ , $I_D=12\text{A}$                     | --- | 10.9 | 22   | nC       |
| $Q_{\text{gs}}$     | Gate-Source Charge <sup>3,4</sup> |  | --- | 1.5  | 3    |          |
| $Q_{\text{gd}}$     | Gate-Drain Charge <sup>3,4</sup>  |  | --- | 4.4  | 9    |          |
| $T_{\text{d(on)}}$  | Turn-On Delay Time <sup>3,4</sup> | $V_{\text{DD}}=30\text{V}$ , $V_{\text{GS}}=10\text{V}$ , $R_G=3.3\Omega$ ,<br>$I_D=1\text{A}$ | --- | 8    | 16   | ns       |
| $T_r$               | Rise Time <sup>3,4</sup>          |  | --- | 12   | 24   |          |
| $T_{\text{d(off)}}$ | Turn-On Delay Time <sup>3,4</sup> |  | --- | 25   | 50   |          |
| $T_f$               | Fall Time <sup>3,4</sup>          |  | --- | 18   | 36   |          |
| $C_{\text{iss}}$    | Input Capacitance                 | $V_{\text{DS}}=30\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $f=1\text{MHz}$                       | --- | 653  | 1300 | pF       |
| $C_{\text{oss}}$    | Output Capacitance                |  | --- | 192  | 380  |          |
| $C_{\text{rss}}$    | Reverse Transfer Capacitance      |  | --- | 27   | 60   |          |
| $R_g$               | Gate Resistance                   | $V_{\text{GS}}=0\text{V}$ , $V_{\text{DS}}=0\text{V}$ , $f=1\text{MHz}$                        | --- | 0.3  | ---  | $\Omega$ |

### Drain-Source Diode Characteristics and Maximum Ratings

| Symbol          | Parameter                          | Conditions   | Min. | Typ. | Max. | Unit |
|-----------------|------------------------------------|--|------|------|------|------|
| $I_s$           | Continuous Source Current          | $V_G=V_D=0\text{V}$ , Force Current                                  | ---  | ---  | 35   | A    |
| $I_{\text{SM}}$ | Pulsed Source Current <sup>3</sup> |  | ---  | ---  | 70   | A    |
| $V_{\text{SD}}$ | Diode Forward Voltage <sup>3</sup> | $V_{\text{GS}}=0\text{V}$ , $I_s=1\text{A}$ , $T_J=25^\circ\text{C}$ | ---  | ---  | 1    | V    |

Note :

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2.  $V_{\text{DD}}=50\text{V}$ ,  $V_{\text{GS}}=10\text{V}$ ,  $L=0.1\text{mH}$ ,  $I_{\text{AS}}=13.5\text{A}$ ,  $R_G=25\Omega$ , Starting  $T_J=25^\circ\text{C}$ .
3. The data tested by pulsed , pulse width  $\leq 300\text{us}$  , duty cycle  $\leq 2\%$ .
4. Essentially independent of operating temperature.

# DEVICE CHARACTERISTICS

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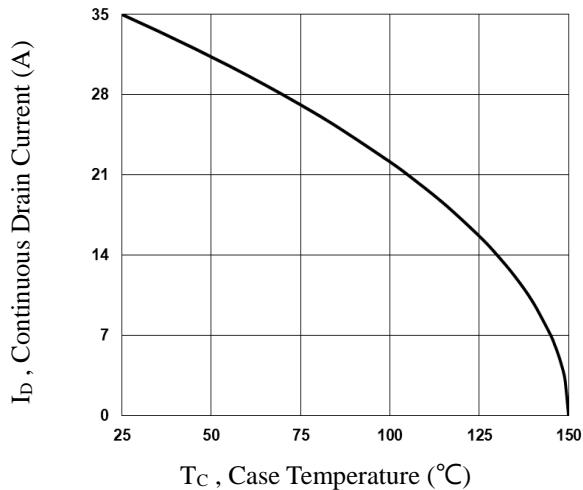


Fig.1 Continuous Drain Current vs.  $T_C$

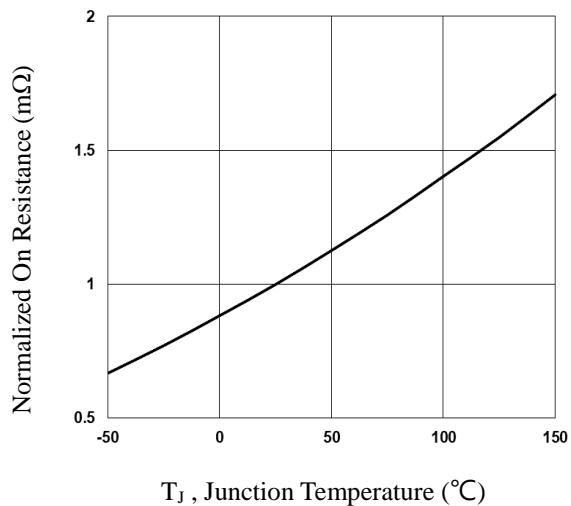


Fig.2 Normalized RDSON vs.  $T_J$

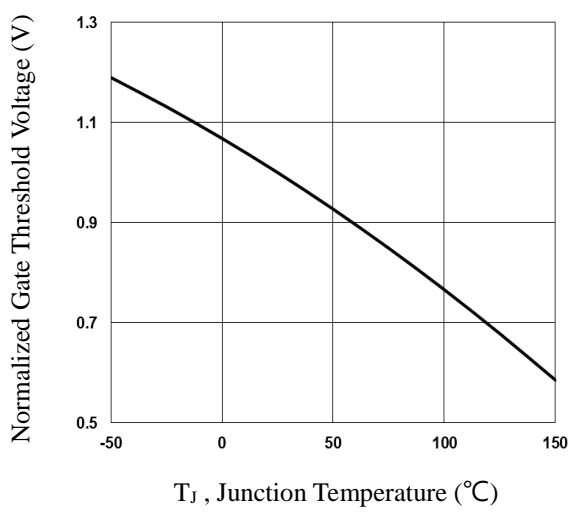


Fig.3 Normalized  $V_{th}$  vs.  $T_J$

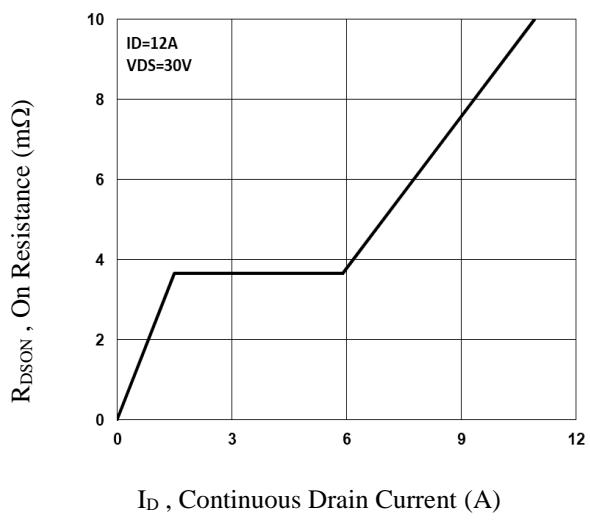


Fig.4 RDSON vs. Continuous Drain Current

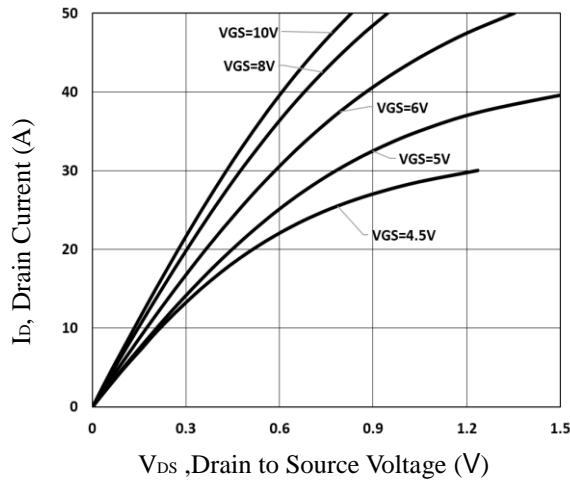


Fig.5 Typical Output Characteristics

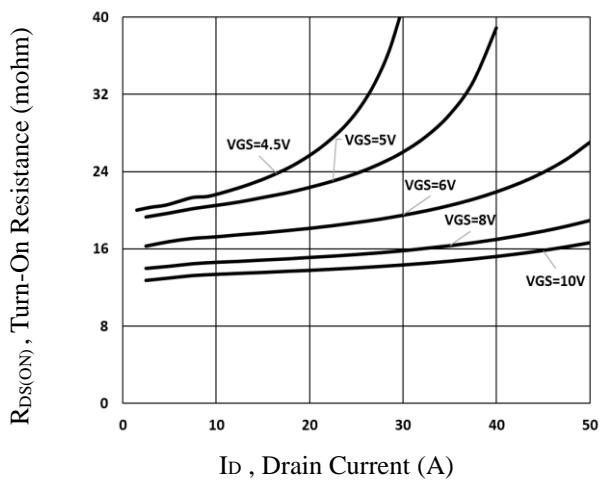


Fig.6 Turn-On Resistance vs.  $I_D$

# DEVICE CHARACTERISTICS

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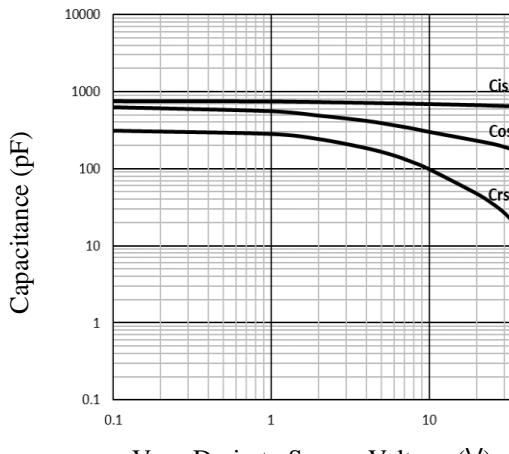


Fig.7 Capacitance Characteristics

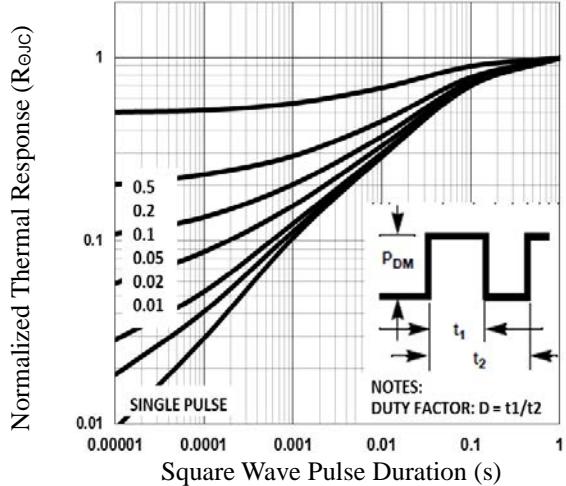


Fig.8 Normalized Transient Response

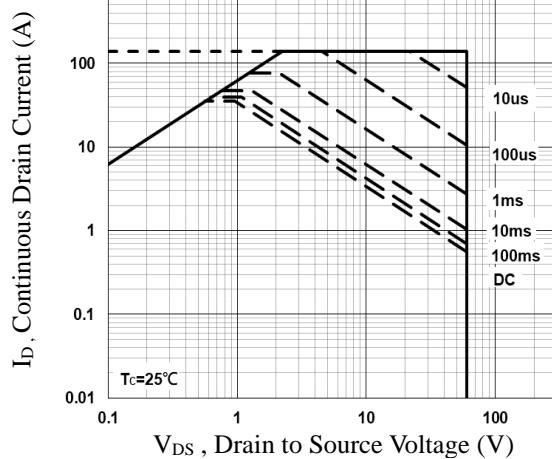


Fig.9 Maximum Safe Operation Area

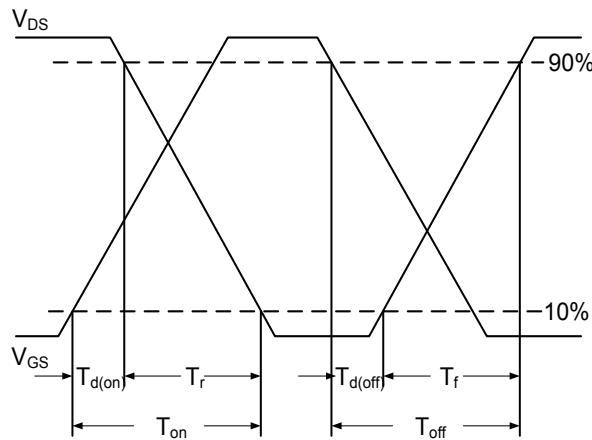


Fig.10 Switching Time Waveform

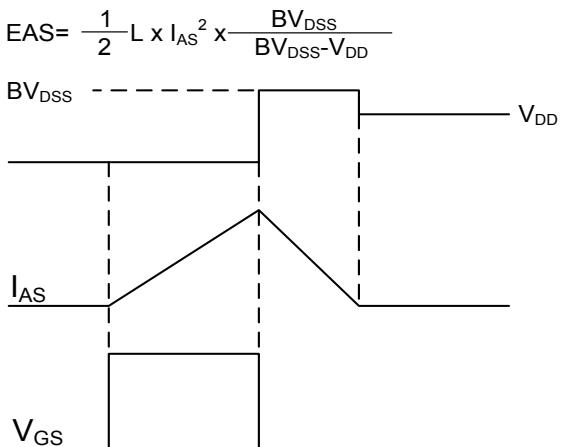
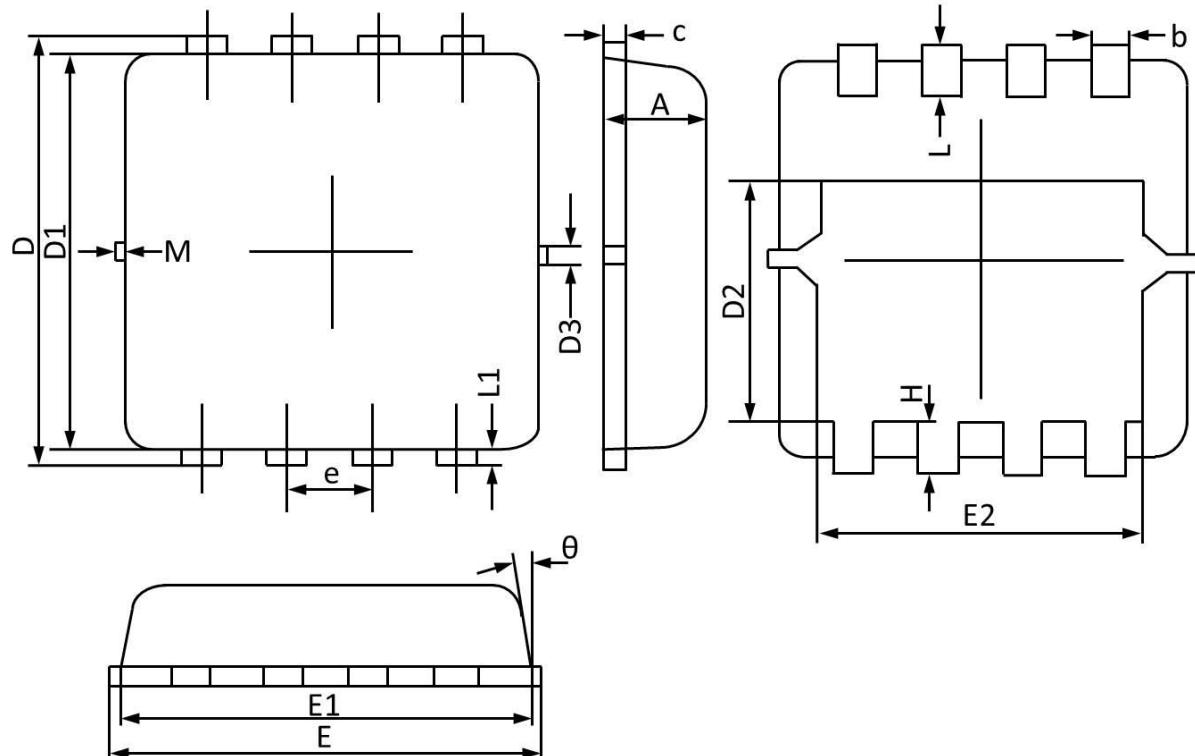


Fig.11 EAS Waveform

# PACKAGE OUTLINE & DIMENSIONS

YS6988Z-5BB

## PPAK3x3 PACKAGE INFORMATION



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 0.700                     | 0.800 | 0.028                | 0.031 |
| b      | 0.250                     | 0.350 | 0.010                | 0.013 |
| c      | 0.100                     | 0.250 | 0.004                | 0.009 |
| D      | 3.250                     | 3.450 | 0.128                | 0.135 |
| D1     | 3.000                     | 3.200 | 0.119                | 0.125 |
| D2     | 1.780                     | 1.980 | 0.070                | 0.077 |
| D3     | 0.130 REF                 |       | 0.005 REF            |       |
| E      | 3.200                     | 3.400 | 0.126                | 0.133 |
| E1     | 3.000                     | 3.200 | 0.119                | 0.125 |
| E2     | 2.390                     | 2.590 | 0.094                | 0.102 |
| e      | 0.650 BSC                 |       | 0.026 BSC            |       |
| H      | 0.300                     | 0.500 | 0.011                | 0.019 |
| L      | 0.300                     | 0.500 | 0.011                | 0.019 |
| L1     | 0.130 REF                 |       | 0.005 REF            |       |
| θ      | 0°                        | 12°   | 0°                   | 12°   |
| M      | 0.150 REF                 |       | 0.006 REF            |       |